# Cascadable Silicon Bipolar MMIC Amplifier

Technical Data

#### **MSA-0270**

#### **Features**

- Cascadable 50  $\Omega$  Gain Block
- 3 dB Bandwidth: DC to 2.8 GHz
- 12.0 dB Typical Gain at 1.0 GHz
- Unconditionally Stable (k>1)
- Hermetic Gold-ceramic Microstrip Package

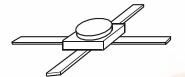
### **Description**

The MSA-0270 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a hermetic, high reliability package. This

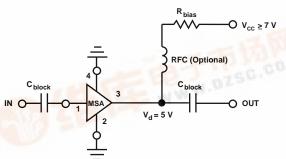
MMIC is designed for use as a general purpose  $50 \Omega$  gain block. Typical applications include narrow and broad band IF and RF amplifiers in industrial and military applications.

The MSA-series is fabricated using HP's 10 GHz ft, 25 GHz f MAX, silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

## 70 mil Package



## **Typical Biasing Configuration**





## MSA-0270 Absolute Maximum Ratings

Parameter	Absolute Maximum <sup>[1]</sup>				
Device Current	60 mA				
Power Dissipation <sup>[2,3]</sup>	325 mW				
RF Input Power	+13dBm				
Junction Temperature	200°C				
Storage Temperature	−65 to 200°C				

Thermal Resistance $[2,4]$ :						
$\theta_{\rm jc} = 120$ °C/W						

#### **Notes:**

- 1. Permanent damage may occur if any of these limits are exceeded.
- 2.  $T_{CASE} = 25$ °C.
- 3. Derate at 8.3 mW/°C for  $T_C > 161$ °C.
- 4. The small spot size of this technique results in a higher, though more accurate determination of  $\theta_{jc}$  than do alternate methods. See MEASURE-MENTS section "Thermal Resistance" for more information.

## Electrical Specifications<sup>[1]</sup>, $T_A = 25$ °C

Symbol	Parameters and Test Conditions:	Units	Min.	Тур.	Max.	
GP	Power Gain ( $ S_{21} ^2$ )	f = 0.1  GHz	dB	11.5	12.5	13.5
$\Delta G_P$	Gain Flatness	f = 0.1  to  1.8  GHz	dB		± 0.6	± 1.0
f <sub>3 dB</sub>	3 dB Bandwidth		GHz		2.8	
VSWR	Input VSWR	f = 0.1  to  3.0  GHz			1.4:1	
vovn	Output VSWR	f = 0.1  to  3.0  GHz			1.4:1	
NF	$50\Omega$ Noise Figure	f = 1.0  GHz	dB		6.5	
P <sub>1 dB</sub>	Output Power at 1 dB Gain Compression	f = 1.0  GHz	dBm		4.5	
IP3	Third Order Intercept Point	f = 1.0  GHz	dBm		17.0	
$t_{\mathrm{D}}$	Group Delay	f = 1.0  GHz	psec		125	
Vd	Device Voltage		V	4.5	5.0	5.5
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-8.0	

#### Note:

1. The recommended operating current range for this device is 18 to 40 mA. Typical performance as a function of current is on the following page.

MSA-0270 Typical Scattering Parameters (Z  $_{0}$  = 50  $\Omega,$   $T_{_{A}}$  = 25  $^{\circ}C,$   $I_{_{d}}$  = 25 mA)

Freq.	S <sub>11</sub>		$\mathbf{S}_{21}$		$\mathbf{S}_{12}$			$\mathbf{S}_{22}$		
GHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	.11	179	12.6	4.26	176	-18.4	.120	1	.12	-8
0.2	.11	174	12.6	4.24	171	-18.6	.117	3	.12	-15
0.4	.10	169	12.5	4.21	162	-18.4	.120	4	.13	-30
0.6	.09	165	12.4	4.17	154	-18.2	.123	5	.14	<del>-4</del> 4
0.8	.08	161	12.3	4.11	146	-18.2	.123	7	.14	<b>-</b> 55
1.0	.06	161	12.2	4.05	137	-18.0	.126	9	.15	-64
1.5	.02	-150	11.7	3.85	116	-17.2	.138	11	.16	-84
2.0	.06	-110	11.1	3.57	96	-16.3	.153	11	.16	-102
2.5	.11	<b>-</b> 112	10.3	3.27	82	-15.7	.165	14	.14	-106
3.0	.17	-134	9.3	2.92	65	-15.2	.174	12	.13	-114
3.5	.22	-147	8.2	2.56	48	-14.7	.185	6	.15	-111
4.0	.26	156	7.0	2.23	33	-14.3	.192	3	.19	-107
5.0	.28	179	4.7	1.72	8	-14.0	.199	<b>-</b> 6	.27	-107
6.0	.30	143	3.0	1.41	<b>-</b> 13	-13.8	.204	-14	.29	-119

A model for this device is available in the DEVICE MODELS section.

# Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)

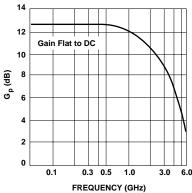


Figure 1. Typical Power Gain vs. Frequency,  $T_A$  = 25°C,  $I_d$  = 25 mA.

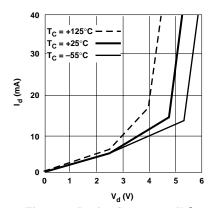


Figure 2. Device Current vs. Voltage.

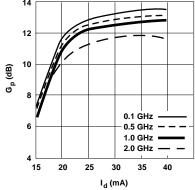


Figure 3. Power Gain vs. Current.

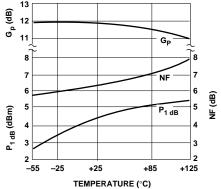


Figure 4. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Mounting Surface Temperature, f = 1.0 GHz.  $L_1 = 25 \text{ mA}$ .

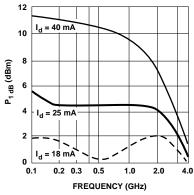
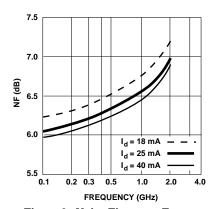


Figure 5. Output Power at 1 dB Gain Compression vs. Frequency.



 $\label{eq:Figure Value} \textbf{Figure 6. Noise Figure vs. Frequency.}$ 

# 70 mil Package Dimensions

